



100V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub>	Ι <sub>D</sub> T <sub>C</sub> = +25°C
100V	32mΩ @ V <sub>GS</sub> = 10V	33A
1000	50mΩ @ V <sub>GS</sub> = 4.5V	26A

#### **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

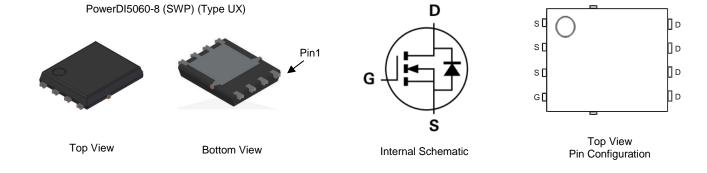
- Synchronous rectifiers
- Backlighting
- Power management functions
- DC-DC converters

#### Features

- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low Input Capacitance
- Fast Switching Speed
- Wettable Flank for Improved Optical Inspection
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES™ DMTH10H032LPSWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities. <u>https://www.diodes.com/quality/product-definitions/</u>

#### **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8 (SWP) (Type UX)
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



## Ordering Information (Note 4)

Part Number	Pookage	Packing		
	Package	Qty.	Carrier	
DMTH10H032LPSWQ-13	PowerDI5060-8 (SWP) (Type UX)	2,500	Tape & Reel	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



## Marking Information



#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V <sub>DSS</sub>	100	V
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 5)	T <sub>C</sub> = +25°C T <sub>C</sub> = +100°C	Ι <sub>D</sub>	33 23	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	132	А
Maximum Continuous Body Diode Forward Current (Not	e 5)	Is	33	А
Pulsed Body Diode Forward Current (10µs Pulse, Duty C	Cycle = 1%)	I <sub>SM</sub>	132	А
Avalanche Current, L = 0.3mH (Note 6)		I <sub>AS</sub>	13	А
Avalanche Energy, L = 0.3mH (Note 6)		E <sub>AS</sub>	25.3	mJ

#### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 7)	T <sub>A</sub> = +25°C	PD	3.4	W
Thermal Resistance, Junction to Ambient (Note 7)		R <sub>0JA</sub>	44	°C/W
Total Power Dissipation (Note 5)	T <sub>C</sub> = +25°C	PD	68	W
Thermal Resistance, Junction to Case (Note 5)		R <sub>θJC</sub>	2.2	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Thermal resistance from junction to soldering point (on the exposed drain pad).

6. I<sub>AS</sub> and E<sub>AS</sub> ratings are based on low frequency and duty cycles to keep  $T_J = +25^{\circ}C$ .

7. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1 inch square copper plate.



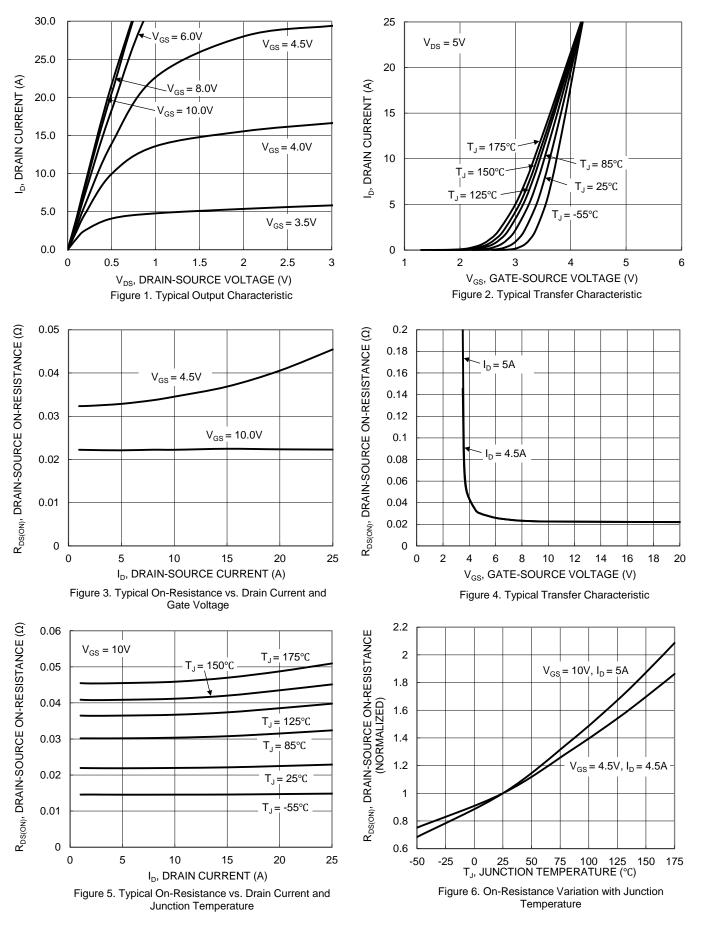
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	·	•		•	•	÷	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	—	—	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	—	—	1	μA	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	—	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.3	—	2.5	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		_	22	32		$V_{GS} = 10V, I_D = 5A$	
	R <sub>DS(ON)</sub>	—	32	50	mΩ	$V_{GS} = 4.5V, I_D = 4.5A$	
Diode Forward Voltage	V <sub>SD</sub>	—	0.8	1	V	$V_{GS} = 0V, I_S = 5A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C <sub>iss</sub>	—	683	—	pF		
Output Capacitance	C <sub>oss</sub>	—	165	_	pF	V <sub>DS</sub> = 50V, V <sub>GS</sub> = 0V f = 1MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	—	6.9	_	pF		
Gate Resistance	R <sub>g</sub>	—	1.2	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	—	6.3	—	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	—	11.9	_	nC		
Gate-Source Charge	Q <sub>gs</sub>	—	2.0	_	nC	$V_{DS} = 50V, I_D = 6A$	
Gate-Drain Charge	Q <sub>gd</sub>	—	3.1	—	nC		
Turn-On Delay Time	t <sub>D(ON)</sub>	—	4.1	—	ns		
Turn-On Rise Time	t <sub>R</sub>	—	4.5	—	ns	$V_{DS} = 50V, R_{L} = 5.85\Omega$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	—	12.5	—	ns	$V_{GS} = 10V, R_g = 3\Omega$	
Turn-Off Fall Time	t <sub>F</sub>	—	9.3	_	ns		
Reverse Recovery Time	t <sub>RR</sub>	—	31.5	—	ns		
Reverse Recovery Charge	Q <sub>RR</sub>		94.6	—	nC	I <sub>F</sub> = 6A, dI/dt = 500A/µs	

Notes:8. Short duration pulse test used to minimize self-heating effect.9. Guaranteed by design. Not subject to product testing.

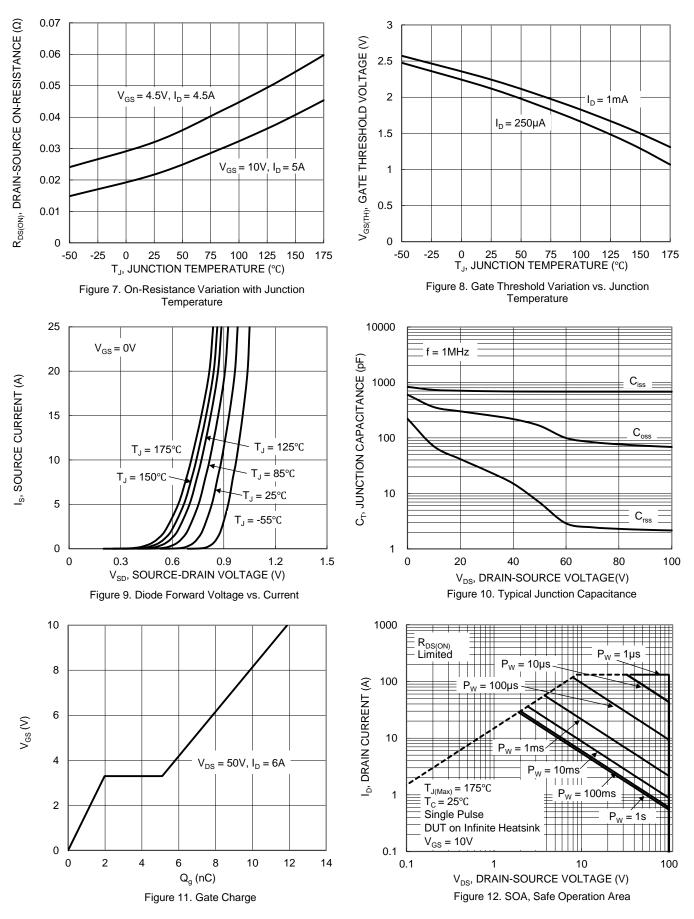


## DMTH10H032LPSWQ





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DMTH10H032LPSWQ Document number: DS44569 Rev. 3 - 2



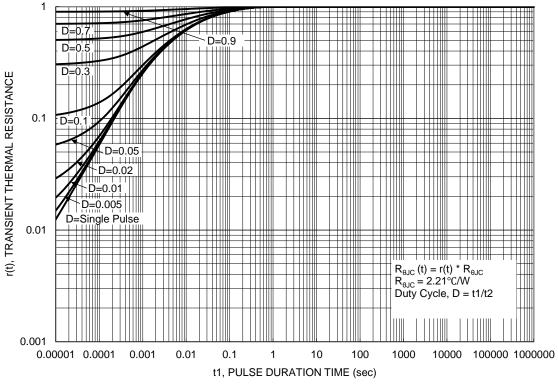
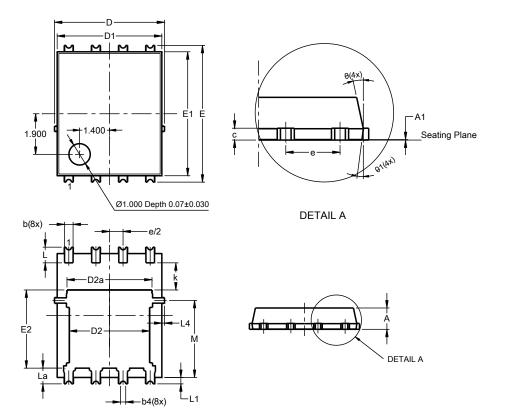


Figure 13. Transient Thermal Resistance



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



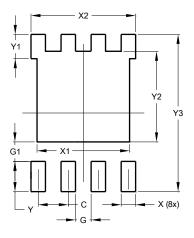
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PowerDI5060-8	(SWP)	(Type UX)

PowerDI5060-8 (SWP)					
(Type UX)					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05	-		
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4	(	).25REF	-		
С	0.230	0.330	0.277		
D		.15 BS0	2		
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78	4.18	3.98		
Е	6	.40 BS0	2		
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1	.27BSC	)		
k	1.05		-		
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L1a	0	.050RE			
L4	0.025	0.225	0.125		
М	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All	All Dimensions in mm				

#### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8 (SWP) (Type UX)



Dimensions	Value
Dimensions	(in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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